

2SA1381/KSA1381

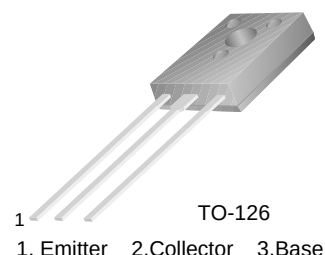
PNP Epitaxial Silicon Transistor

Applications

- Audio, Voltage Amplifier and Current Source
- CRT Display, Video Output
- General Purpose Amplifier

Features

- High Voltage : $V_{CEO} = -300V$
- Low Reverse Transfer Capacitance : $C_{re} = 2.3pF$ at $V_{CB} = -30V$
- Excellent Gain Linearity for low THD
- High Frequency: 150MHz
- Full thermal and electrical Spice models are available
- Complement to 2SC3503/KSC3503



Absolute Maximum Ratings* $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
BV_{CBO}	Collector-Base Voltage	-300	V
BV_{CEO}	Collector-Emitter Voltage	-300	V
BV_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current(DC)	-100	mA
I_{CP}	Collector Current(Pulse)	-200	mA
P_C	Total Device Dissipation, $T_C = 25^\circ C$ $T_C = 125^\circ C$	7 1.2	W W
T_J, T_{STG}	Junction and Storage Temperature	- 55 ~ +150	$^\circ C$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* $T_a = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	17.8	$^\circ C/W$

* Device mounted on minimum pad size

h_{FE} Classification

Classification	C	D	E	F
h_{FE}	40 ~ 80	60 ~ 120	100 ~ 200	160 ~ 320

Electrical Characteristics* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = -10\mu\text{A}, I_E = 0$	- 300			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -1\text{mA}, I_B = 0$	- 300			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu\text{A}, I_C = 0$	- 5			V
I_{CBO}	Collector Cut-off Current	$V_{CB} = -200\text{V}, I_E = 0$			- 0.1	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = -4\text{V}, I_C = 0$			- 0.1	μA
h_{FE}	DC Current Gain	$V_{CE} = -10\text{V}, I_C = -10\text{mA}$	40		320	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -20\text{mA}, I_B = -2\text{mA}$			- 0.6	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -20\text{mA}, I_B = -2\text{mA}$			- 1	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -30\text{V}, I_C = -10\text{mA}$		150		MHz
C_{ob}	Output Capacitance	$V_{CB} = -30\text{V}, f = 1\text{MHz}$		3.1		pF
C_{re}	Reverse Transfer Capacitance	$V_{CB} = -30\text{V}, f = 1\text{MHz}$		2.3		pF

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycles $\leq 2\%$ **Ordering Information**

Part Number*	Marking	Package	Packing Method	Remarks
2SA1381CSTU	2SA1381C	TO-126	TUBE	hFE1 C grade
2SA1381DSTU	2SA1381D	TO-126	TUBE	hFE1 D grade
2SA1381ESTU	2SA1381E	TO-126	TUBE	hFE1 E grade
2SA1381FSTU	2SA1381F	TO-126	TUBE	hFE1 F grade
KSA1381CSTU	A1381C	TO-126	TUBE	hFE1 C grade
KSA1381DSTU	A1381D	TO-126	TUBE	hFE1 D grade
KSA1381ESTU	A1381E	TO-126	TUBE	hFE1 E grade
KSA1381FSTU	A1381F	TO-126	TUBE	hFE1 F grade

* 1. Affix "-S-" means the standard TO126 Package.(see package dimensions). If the affix is "-STS-" instead of "-S-", that mean the short-lead TO126 package.
2. Suffix "-TU" means the tube packing. The Suffix "TU" could be replaced to other suffix character as packing method.

Typical Characteristics

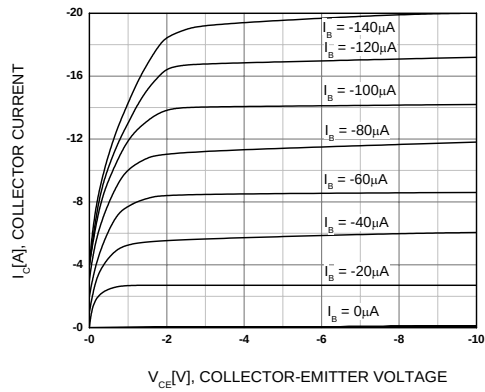


Figure 1. Static Characteristic

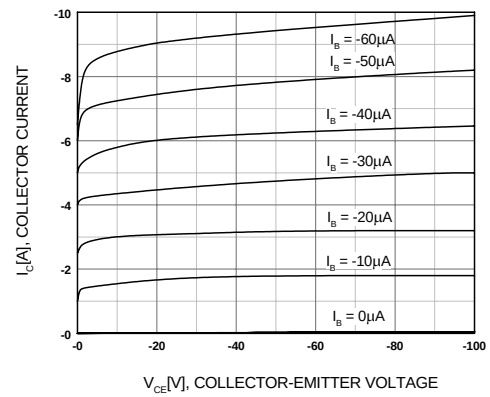


Figure 2. Static Characteristic

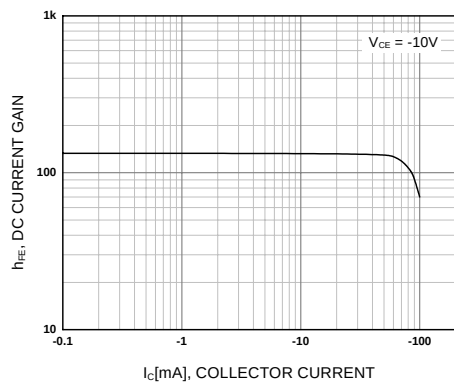


Figure 3. DC current Gain

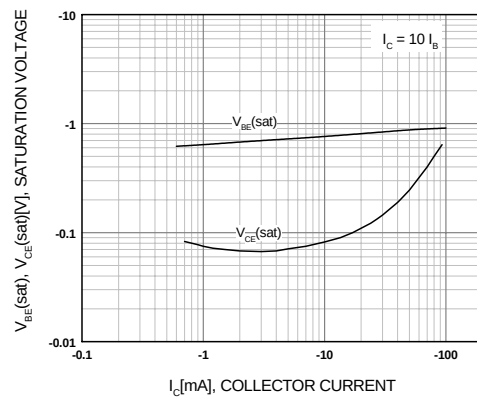


Figure 4. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

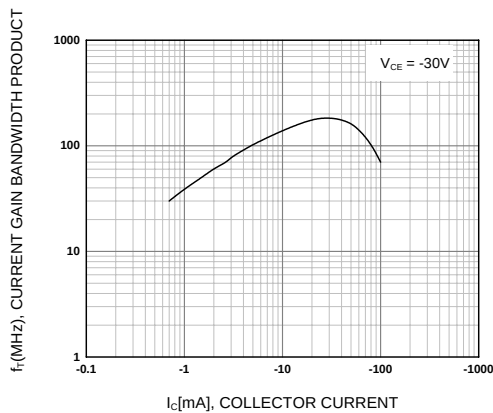


Figure 5. Current Gain Bandwidth Product

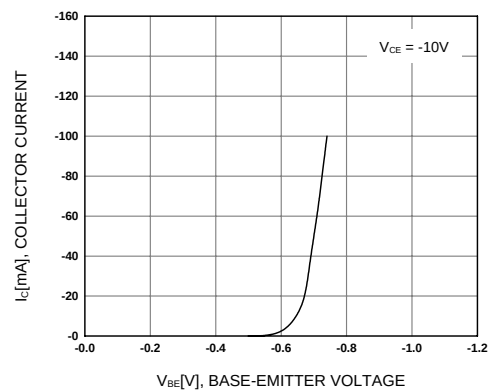


Figure 6. Base-Emitter On Voltage

Typical Characteristics (Continued)

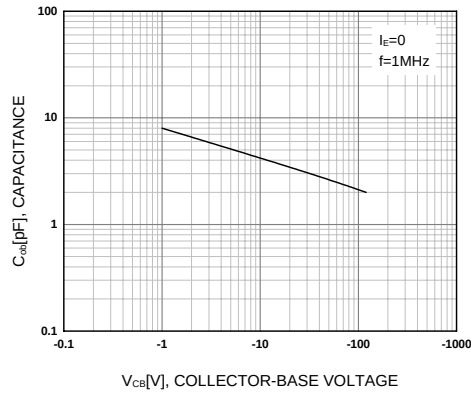


Figure 7. Collector Output Capacitance

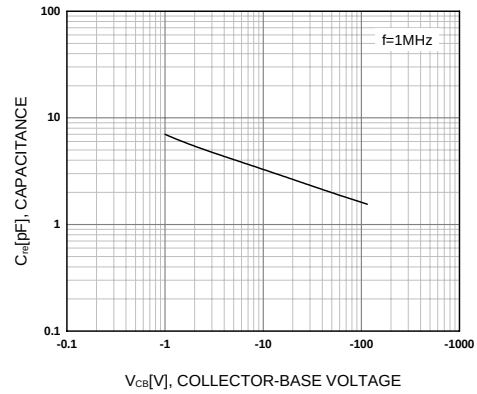


Figure 8. Reverse Transfer Capacitance

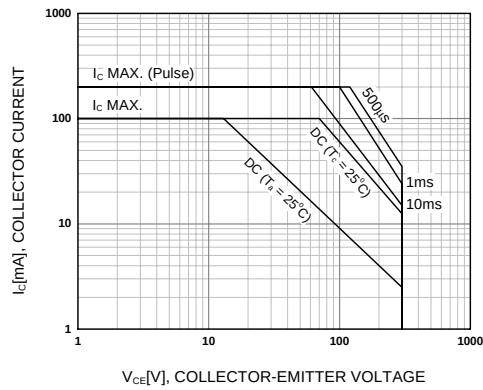


Figure 9. Safe Operating Area

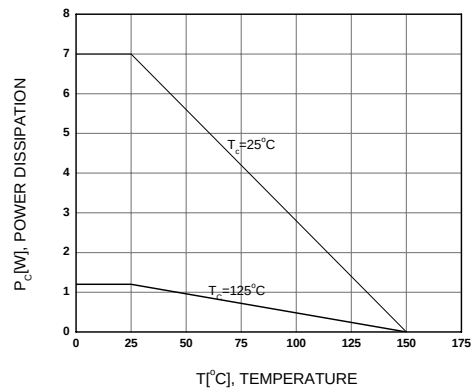
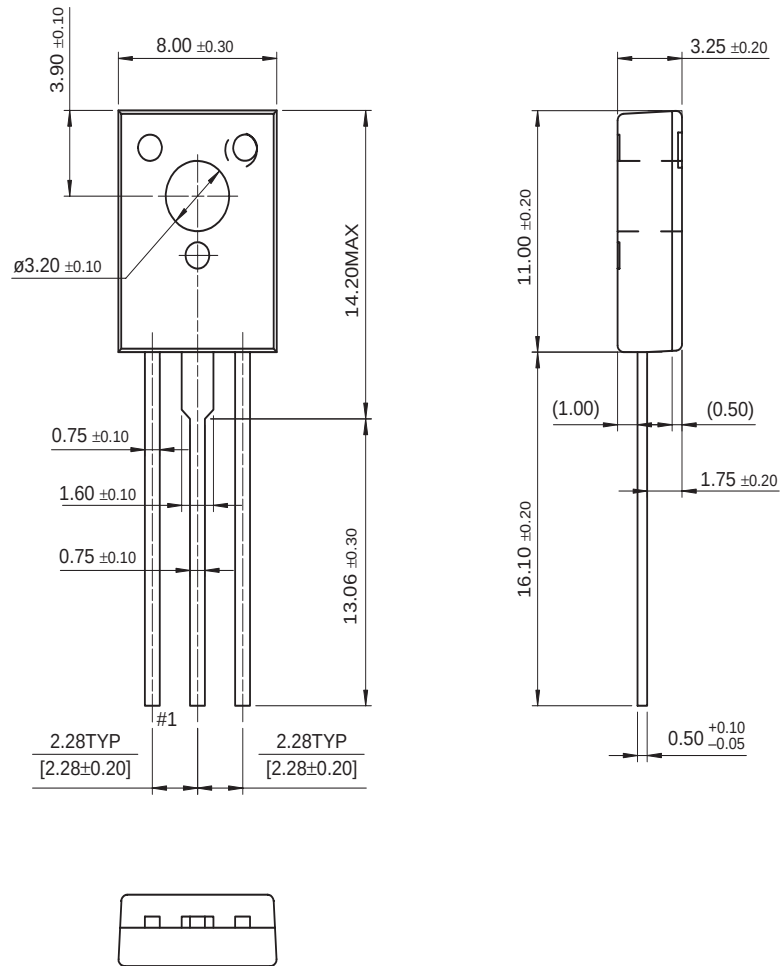


Figure 10. Power Derating

Package Dimensions

TO-126



Dimensions in Millimeters



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